

## KSD1020

## **Audio Frequency Amplifier**

Complement to KSB810



1.Emitter 2. Collector 3. Base

# **NPN Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
$V_{CBO}$	Collector-Base Voltage	30	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V	
I <sub>C</sub>	Collector Current (DC)	700	mA	
I <sub>CP</sub>	* Collector Current (Pulse)	1.0	Α	
P <sub>C</sub>	Collector Power Dissipation	350	mW	
TJ	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C	

<sup>\*</sup> PW≤10ms, Duty Cycle≤50%

## Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =30V, $I_{E}$ =0			100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ =5V, $I_{C}$ =0			100	nA
h <sub>FE1</sub>	* DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	120	200	400	
$h_{FE2}$		V <sub>CE</sub> =1V, I <sub>C</sub> =700mA	35	140		
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA	600	640	700	mV
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =700mA, I <sub>B</sub> =70mA		0.2	0.4	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =700mA, I <sub>B</sub> =70mA		0.95	1.2	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =6V, I <sub>E</sub> =0, f=1MHz		13	25	pF
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA	50	170		MHz
	Dules Tests DWG550.cs Duty Coules 200					l

<sup>\*</sup> Pulse Test: PW≤350μs, Duty Cycle≤ 2%

## h<sub>FE1</sub> Classification

Classification	Y	G
h <sub>FE1</sub>	120 ~ 240	200 ~ 400

# **Typical Characteristics**

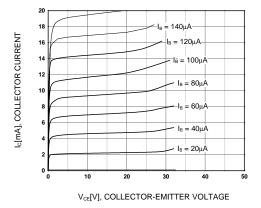


Figure 1. Static Characteristic

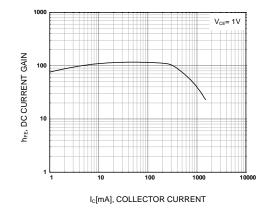


Figure 2. DC current Gain

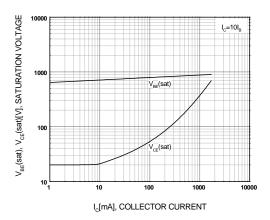


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

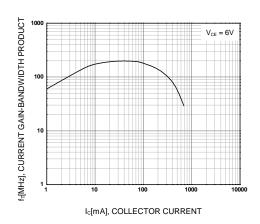
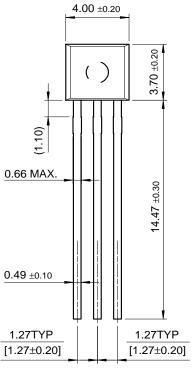
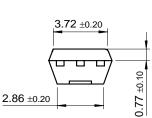


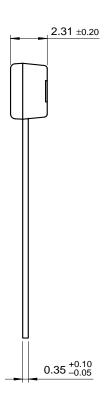
Figure 4. Current Gain-Bandwidth Product

# **Package Dimensions**

# **TO-92S**







Dimensions in Millimeters

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Coo	IFET™	FPS™	MICROCOUPLER™	PowerSaver™	SuperSOT™-3
CR	OSSVOLT™	FRFET™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
DO	ЛЕ™	GlobalOptoisolator™	MicroPak™	QFET <sup>®</sup>	SuperSOT™-8
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$E^2C$	MOS™	HiSeC™	MSX <sup>TM</sup>	QT Optoelectronics™	TinyLogic <sup>®</sup>
EnS	igna™	I <sup>2</sup> C <sup>TM</sup>	MSXPro™	Quiet Series™	TINYOPTO™
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Acro	ss the board.	. Around the world.™	OCXPro™	RapidConnect™	UHC™
The	Power Franc	hise <sup>®</sup>	OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	UltraFET <sup>®</sup>
Programmable Active Droop™		OPTOPLANAR™	SMART START™	VCX <sup>TM</sup>	
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